Operational Amplifier, Rail-to-Rail, 3.5 MHz, Wide Supply

The NCS2004 operational amplifier provides rail–to–rail output operation. The output can swing within 70 mV to the positive rail and 30 mV to the negative rail. This rail–to–rail operation enables the user to make optimal use of the entire supply voltage range while taking advantage of 3.5 MHz bandwidth. The NCS2004 can operate on supply voltage as low as 2.5 V over the temperature range of –40°C to 125°C . The high bandwidth provides a slew rate of 2.4 V/µs while only consuming a typical 390 µA of quiescent current. Likewise the NCS2004 can run on a supply voltage as high as 16 V making it ideal for a broad range of battery operated applications. Since this is a CMOS device it has high input impedance and low bias currents making it ideal for interfacing to a wide variety of signal sensors. In addition it comes in either a small SC–88A or UDFN package allowing for use in high density PCB's.

Features

• Rail-To-Rail Output

• Wide Bandwidth: 3.5 MHz

• High Slew Rate: 2.4 V/μs

• Wide Power Supply Range: 2.5 V to 16 V

Low Supply Current: 390 μA
Low Input Bias Current: 45 pA

• Wide Temperature Range: -40°C to 125°C

• Small Packages: 5-Pin SC-88A and UDFN6 1.6x1.6

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

Notebook Computers

• Portable Instruments



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MARKING DIAGRAMS



SC-88A (SC-70-5) SN SUFFIX CASE 419A



ADK = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)



UDFN6 CASE 517AP



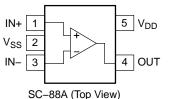
xx = Specific Device Code AA for NCS2004 AC for NCS2004A

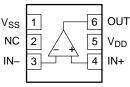
M = Date Code

= Pb–Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS





UDFN (Top View)

ORDERING INFORMATION

Device	Package	Shipping [†]
NCS2004SQ3T2G	SC-88A (Pb-Free)	3000 / Tape & Reel
NCS2004MUTAG, NCS2004AMUTAG	UDFN6 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Symbol	Rating	Value	Unit
V_{DD}	Supply Voltage	16.5	V
V _{ID}	Input Differential Voltage	± Supply Voltage	V
VI	Input Common Mode Voltage Range	-0.2 V to (V _{DD} + 0.2 V)	V
I _I	Maximum Input Current	±10	mA
IO	Output Current Range	±100	mA
	Continuous Total Power Dissipation (Note 1)	200	mW
TJ	Maximum Junction Temperature	150	°C
θ_{JA}	Thermal Resistance	333	°C/W
T _{stg}	Operating Temperature Range (free–air)	-40 to 125	°C
T _{stg}	Storage Temperature	-65 to 150	°C
	Mounting Temperature (Infrared or Convection – 20 sec)	260	°C
V _{ESD}	Machine Model Human Body Model	300 2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

DC ELECTRICAL CHARACTERISTICS (V_{DD} = 2.5 V, 3.3 V, 5 V and ± 5 V, T_A = 25°C, $R_L \ge 10$ k Ω unless otherwise noted)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Input Offset Voltage	V _{IO}	VIC = $V_{DD}/2$, $V_O = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, R_S	= 50 Ω		0.5	5.0	mV
(NCS2004)		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$				7.0	1
Input Offset Voltage	V _{IO}	VIC = $V_{DD}/2$, $V_O = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, R_S	= 50 Ω			3.0	mV
(NCS2004A)		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$				5.0	
Offset Voltage Drift	ICV _{OS}	VIC = $V_{DD}/2$, $V_O = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, R_S	= 50 Ω		2.0		μV/°C
Common Mode	CMRR	$0 \text{ V} \leq \text{VIC} \leq \text{V}_{DD} - 1.35 \text{ V}, R_S = 50 \Omega$	V _{DD} = 2.5 V	55	94		dB
Rejection Ratio		$T_A = -40$ °C to +125°C		52]
		$0 \text{ V} \leq \text{VIC} \leq \text{V}_{DD} - 1.35 \text{ V}, R_S = 50 \Omega$	$V_{DD} = 5 V$	65	130]
		$T_A = -40$ °C to +125°C		62			
		$0 \text{ V} \leq \text{VIC} \leq \text{V}_{DD} - 1.35 \text{ V}, R_S = 50 \Omega$		69	140		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		66			
Power Supply	PSRR	V_{DD} = 2.5 V to 16 V, VIC = $V_{DD}/2$, No Load		70	135		dB
Rejection Ratio		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		65			
Large Signal	A_{VD}	$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$	V _{DD} = 2.5 V	90	130		dB
Voltage Gain		$T_A = -40$ °C to +125°C		76			
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$	V _{DD} = 3.3 V	92	123		
		$T_A = -40$ °C to +125°C		76			
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$	V _{DD} = 5 V	95	127		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		86			
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$	$V_{DD} = \pm 5 \text{ V}$	95	130		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$]	90			

Continuous short circuit operation to ground at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 45 mA over long term may adversely affect reliability. Shorting output to either V+ or V- will adversely affect reliability.

DC ELECTRICAL CHARACTERISTICS (V_{DD} = 2.5 V, 3.3 V, 5 V and \pm 5 V, T_A = 25°C, R_L \geq 10 k Ω unless otherwise noted)

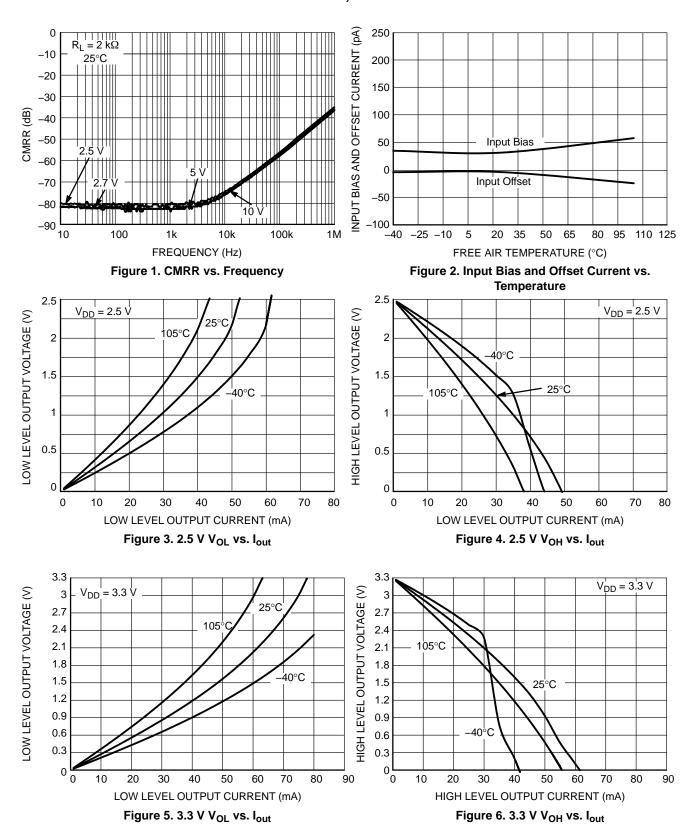
Parameter	Symbol	Conditions	Conditions		Тур	Max	Unit
Input Bias Current	I _B	$V_{DD} = 5 \text{ V}, \text{ VIC} = V_{DD}/2, V_{O} = V_{DD}/2,$	T _A = 25°C		45	150	pА
		$R_S = 50 \Omega$	T _A = 125°C			1000	
Input Offset Current	I _{IO}	$V_{DD} = 5 \text{ V}, \text{ VIC} = V_{DD}/2, V_{O} = V_{DD}/2,$	T _A = 25°C		45	150	pА
		$R_S = 50 \Omega$	T _A = 125°C			1000	
Differential Input Resistance	r _{i(d)}				1000		GΩ
Common-mode Input Capacitance	C _{IC}	f = 21 kHz			8.0		pF
Output Swing	V _{OH}	$VIC = V_{DD}/2$, $I_{OH} = -1$ mA	V _{DD} = 2.5 V	2.35	2.43		V
(High–level)		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7	2.28			
		$VIC = V_{DD}/2$, $I_{OH} = -1$ mA	V _{DD} = 3.3 V	3.15	3.21		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		3.00			
		$VIC = V_{DD}/2$, $I_{OH} = -1$ mA	V _{DD} = 5 V	4.8	4.93		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		4.75			
		$VIC = V_{DD}/2$, $I_{OH} = -1$ mA	$V_{DD} = \pm 5 \text{ V}$	4.92	4.96		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		4.9			
		$VIC = V_{DD}/2, I_{OH} = -5 \text{ mA}$	V _{DD} = 2.5 V	1.7	2.14		V
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7	1.5			
		$VIC = V_{DD}/2, I_{OH} = -5 \text{ mA}$	V _{DD} = 3.3 V	2.5	2.89		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7	2.1			
		$VIC = V_{DD}/2, I_{OH} = -5 \text{ mA}$	V _{DD} = 5 V	4.5	4.68		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	V _{DD} = ±5 V	4.35			
		$VIC = V_{DD}/2$, $I_{OH} = -5$ mA		4.7	4.78		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		4.65			
Output Swing	V _{OL}	$VIC = V_{DD}/2$, $I_{OL} = -1$ mA	V _{DD} = 2.5 V		0.03	0.15	V
(Low-level)		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$				0.22	
		$VIC = V_{DD}/2$, $I_{OL} = -1$ mA	V _{DD} = 3.3 V		0.03	0.15	
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7			0.22	
		$VIC = V_{DD}/2$, $I_{OL} = -1$ mA	V _{DD} = 5 V		0.03	0.1	
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7			0.15	
		$VIC = V_{DD}/2$, $I_{OL} = -1$ mA	$V_{DD} = \pm 5 \text{ V}$		0.05	0.08	
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7			0.1	
		$VIC = V_{DD}/2$, $I_{OL} = -5$ mA	V _{DD} = 2.5 V		0.15	0.7	V
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7			1.1	
		$VIC = V_{DD}/2, I_{OL} = -5 \text{ mA}$	V _{DD} = 3.3 V		0.13	0.7	
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7			1.1	
		$VIC = V_{DD}/2, I_{OL} = -5 \text{ mA}$	V _{DD} = 5 V		0.13	0.4	
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7			0.5	
		$VIC = V_{DD}/2, I_{OL} = -5 \text{ mA}$	V _{DD} = ±5 V		0.16	0.3	
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	7			0.35	

DC ELECTRICAL CHARACTERISTICS (V_{DD} = 2.5 V, 3.3 V, 5 V and \pm 5 V, T_A = 25°C, R_L \geq 10 k Ω unless otherwise noted)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Output Current	I _O	$V_O = 0.5 \text{ V from rail}, V_{DD} = 2.5 \text{ V}$	Positive rail		4.0		mA
			Negative rail		5.0		
		$V_O = 0.5 \text{ V from rail}, V_{DD} = 5 \text{ V}$	Positive rail		7.0		
			Negative rail		8.0		
		$V_O = 0.5 \text{ V from rail}, V_{DD} = 10 \text{ V}$	Positive rail		13		
			Negative rail		12		
Power Supply	I _{DD}	$V_O = V_{DD}/2$	V _{DD} = 2.5 V		380	560	μΑ
Quiescent Current			V _{DD} = 3.3 V		385	620	
			V _{DD} = 5 V		390	660	
			V _{DD} = 10 V		400	800	
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$				1000	

AC ELECTRICAL CHARACTERISTICS (V_{DD} = 2.5 V, 5 V, & ± 5 V, T_A = 25°C, and R_L \geq 10 k Ω unless otherwise noted)

Parameter	Symbol	Conditions		Min	Тур	Max	Unit
Unity Gain	UGBW	$R_L = 2 \text{ k}\Omega, C_L = 10 \text{ pF}$	V _{DD} = 2.5 V		3.2		MHz
Bandwidth			V _{DD} = 5 V to 10 V		3.5		
Slew Rate at Unity	SR	$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, $C_L = 50 \text{ pF}$	V _{DD} = 2.5 V	1.35	2.0		V/μS
Gain		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$	1	1			1
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, $C_L = 50 \text{ pF}$	V _{DD} = 5 V	1.45	2.3		
		$T_A = -40$ °C to +125°C		1.2			1
		$V_{O(pp)} = V_{DD}/2$, $R_L = 10 \text{ k}\Omega$, $C_L = 50 \text{ pF}$	$V_{DD} = \pm 5 \text{ V}$	1.8	2.6		
		$T_A = -40^{\circ}\text{C to } +125^{\circ}\text{C}$		1.3			
Phase Margin	θ_{m}	$R_L = 2 \text{ k}\Omega, C_L = 10 \text{ pF}$			45		0
Gain Margin		$R_L = 2 \text{ k}\Omega$, $C_L = 10 \text{ pF}$			14		dB
Settling Time to 0.1%	t _S	V-step(pp) = 1 V, AV = -1, R_L = 2 k Ω , C_L = 10 pF	V _{DD} = 2.5 V		2.9		μS
		V -step(pp) = 1 V, AV = -1, R _L = 2 kΩ, C_L = 68 pF	V _{DD} = 5 V, ± 5 V		2.0		
Total Harmonic	THD+N	$V_{DD} = 2.5 \text{ V}, V_{O(pp)} = V_{DD}/2, R_L = 2 \text{ k}\Omega,$ f = 10 kHz	AV = 1		0.004		%
Distortion plus Noise			AV = 10		0.04		1
			AV = 100		0.3		
		$V_{DD} = 5 \text{ V}, \pm 5 \text{ V}, V_{O(pp)} = V_{DD}/2,$	AV = 1		0.004		
		$R_L = 2 \text{ k}\Omega, f = 10 \text{ kHz}^{\text{T}}$	AV = 10		0.04		
			AV = 100		0.03		
Input-Referred	e _n	f = 1 kHz			30		nV/√Hz
Voltage Noise		f = 10 kHz			20		
Input-Referred Current Noise	i _n	f = 1 kHz			0.6		fA/√Hz



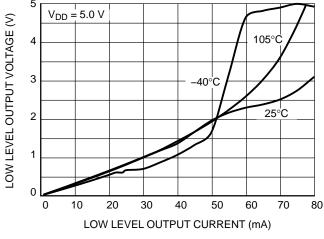


Figure 7. V_{OL} vs. I_{out}

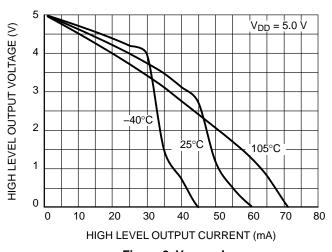


Figure 8. V_{OH} vs. I_{out}

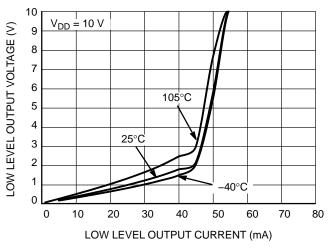


Figure 9. 10 V V_{OL} vs. I_{out}

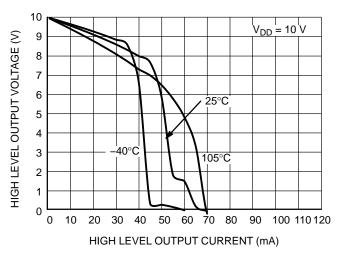


Figure 10. 10 V V_{OH} vs. I_{out}

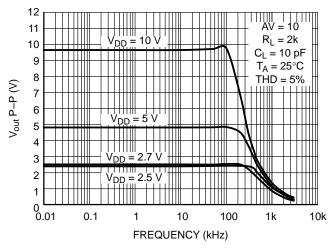


Figure 11. Peak-to-Peak Output vs. Supply vs. Frequency

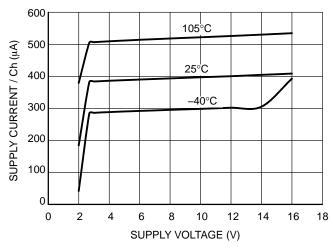


Figure 12. Supply Current vs. Supply Voltage

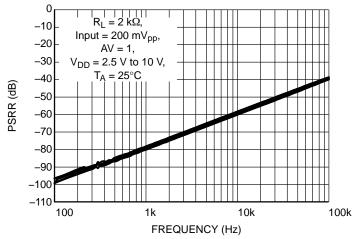


Figure 13. PSRR vs. Frequency

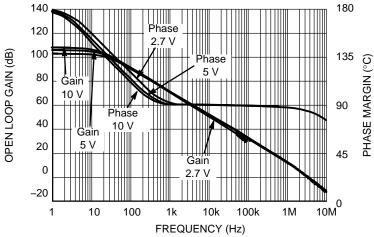


Figure 14. Open Loop Gain and Phase vs. Frequency

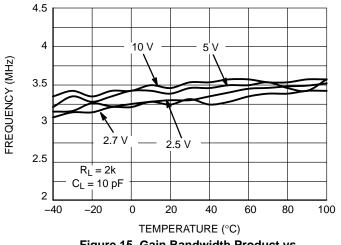


Figure 15. Gain Bandwidth Product vs. Temperature

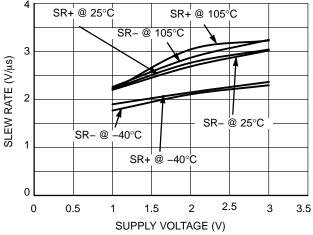


Figure 16. Slew Rate vs. Supply Voltage

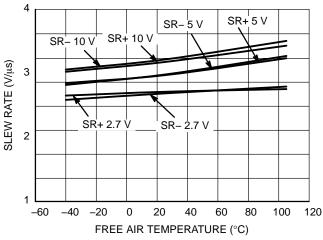


Figure 17. Slew Rate vs. Temperature

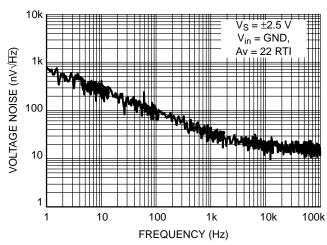


Figure 18. Voltage Noise vs. Frequency

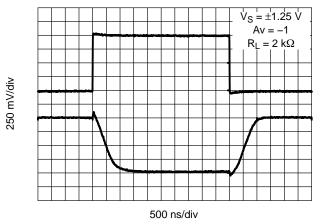


Figure 19. 2.5 V Inverting Large Signal Pulse Response

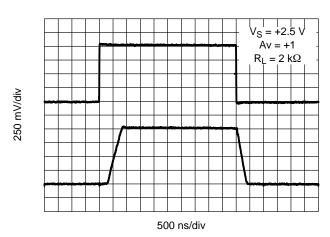


Figure 20. 2.5 V Non-Inverting Large Signal Pulse Response

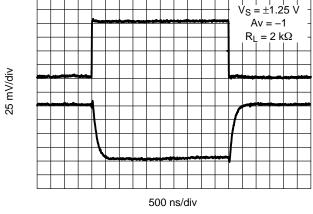


Figure 21. 2.5 V Inverting Small Signal Pulse Response

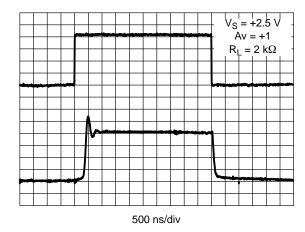


Figure 22. 2.5 V Non-Inverting Small Signal Pulse Response

25 mV/div

250 mV/div

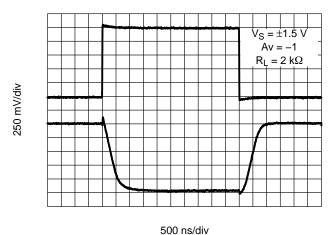


Figure 23. 3 V Inverting Large Signal Pulse Response

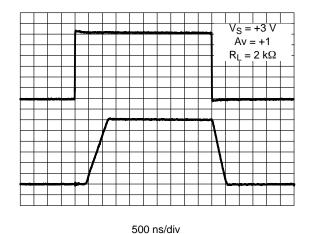


Figure 24. 3 V Non-Inverting Large Signal Pulse Response

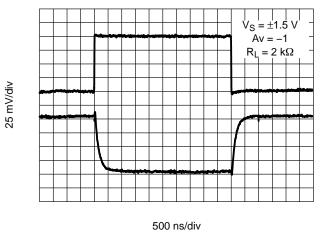


Figure 25. 3 V Inverting Small Signal Pulse Response

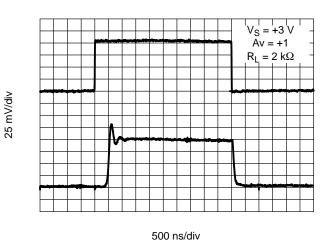


Figure 26. 3 V Non-Inverting Small Signal Pulse Response

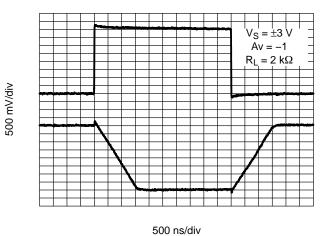


Figure 27. 6 V Inverting Large Signal Pulse Response

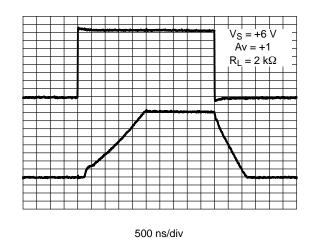


Figure 28. 6 V Non-Inverting Large Signal Pulse Response

500 mV/div

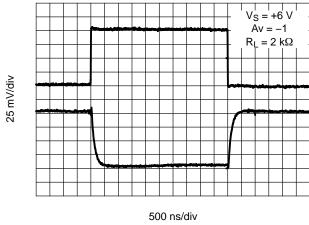


Figure 29. 6 V Inverting Small Signal Pulse Response

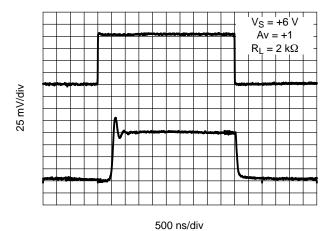


Figure 30. 6 V Non-Inverting Small Signal Pulse Response

APPLICATIONS

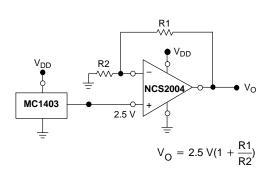


Figure 31. Voltage Reference

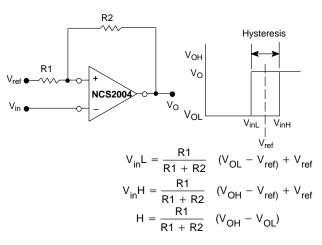


Figure 33. Comparator with Hysteresis

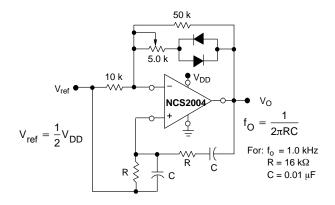
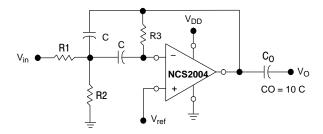


Figure 32. Wien Bridge Oscillator



Given: f_0 = center frequency $A(f_0)$ = gain at center frequency

Choose value
$$f_0$$
, $\frac{C}{Q}$
Then: $R3 = \frac{Q}{\pi f_0 C}$
 $R1 = \frac{R3}{2 A(f_0)}$
 $R2 = \frac{R1 R3}{40^2 R1 - R3}$

For less than 10% error from operational amplifier, $((Q_O f_O)/BW) < 0.1$ where f_O and BW are expressed in Hz. If source impedance varies, filter may be preceded with voltage follower buffer to stabilize filter parameters.

Figure 34. Multiple Feedback Bandpass Filter





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SC-88A (SC-70-5/SOT-353) CASE 419A-02 ISSUE M

DATE 11 APR 2023

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- 419A-01 DBSDLETE, NEW STANDARD 419A-02
- DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,

DIM	MILLIMETERS			
INITU	MIN.	N□M.	MAX.	
А	0.80	0.95	1.10	
A1			0.10	
A3	0.20 REF			
b	0.10	0.20	0.30	
C	0.10		0.25	
D	1.80	2.00	2,20	
Е	2.00	2.10	2.20	
E1	1.15	1.25	1.35	
е	0.65 BSC			
L	0.10	0.15	0.30	

5X b

→ 0.2 M B M

- PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.1016MM PER SIDE.

	L — M			
<u> </u>	0.50	5		

RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

5. COLLECTOR

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:
PIN 1. BASE	PIN 1. ANODE	PIN 1. ANODE 1	PIN 1. SOURCE 1	PIN 1. CATHODE
2. EMITTER	2. EMITTER	2. N/C	2. DRAIN 1/2	2. COMMON ANODE
3. BASE	3. BASE	3. ANODE 2	SOURCE 1	3. CATHODE 2
4. COLLECTOR	COLLECTOR	CATHODE 2	4. GATE 1	4. CATHODE 3
COLLECTOR	CATHODE	CATHODE 1	5. GATE 2	5. CATHODE 4
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	Note: Please refer to datasheet for
PIN 1. EMITTER 2	PIN 1. BASE	PIN 1. CATHODE	PIN 1. ANODE	atula callout. If atula tupa is not called
2. BASE 2	2. EMITTER	2. COLLECTOR	2. CATHODE	style callout. If style type is not called
3. EMITTER 1	3. BASE	3. N/C	3. ANODE	out in the datasheet refer to the device
4. COLLECTOR	COLLECTOR	4. BASE	4. ANODE	datasheet pinout or pin assignment.
COLLECTOR 2/BASE 1	5. COLLECTOR	5. EMITTER	5. ANODE	datasheet pinout of pin assignment.

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DESCRIPTION:	SC-88A (SC-70-5/SOT-353)		PAGE 1 OF 1		

5. EMITTER

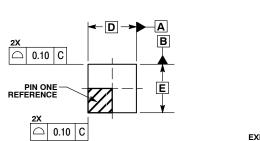
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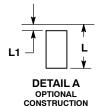
5. COLLECTOR 2/BASE 1

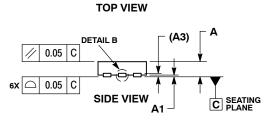
DATE 26 OCT 2007

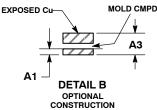


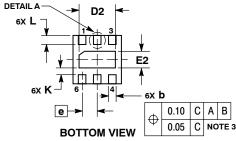




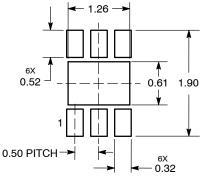








SOLDERMASK DEFINED MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

NOTES:

- DIMENSIONING AND TOLERANCING PER
 ASME V14 5M 1994
- ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION & APPLIES TO PLATED TERMINAL
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL.
- 0.30 mm FROM TERMINAL.4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.45	0.55		
A1	0.00	0.05		
А3	0.13	REF		
b	0.20	0.30		
D	1.60	BSC		
E	1.60	BSC		
е	0.50	BSC		
D2	1.10	1.30		
E2	0.45	0.65		
K	0.20			
L	0.20	0.40		
L1	0.00	0.15		

GENERIC MARKING DIAGRAM*



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M = Date Code

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*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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DESCRIPTION:	6 PIN UDFN, 1.6X1.6, 0.5P		PAGE 1 OF 1		

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^{*}For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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